

isc Silicon PNP Power Transistor

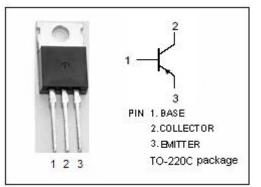
KSB596

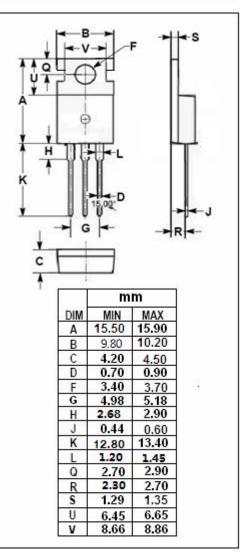
DESCRIPTION

- Low Collector Saturation Voltage :V_{CE(sat)}= -1.7(V)(Max)@I_C= -3A
- Collector-Emitter Breakdown Voltage-: V_{(BR)CEO}= -80V(Min)
- Complement to Type KSD526
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- · Power amplifier applications.
- Recommended for 20~25W high-fidelity audio frequency amplifier output stage.





ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	-80	V
Vceo	Collector-Emitter Voltage	-80	V
V_{EBO}	Emitter-Base Voltage	-5	V
lc	Collector Current-Continuous	-4	А
lв	Base Current-Continuous	-0.4	А
Pc	Total Power Dissipation @ Tc=25℃	30	W
TJ	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C
	1	1	

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INCHANGE SEMICONDUCTOR

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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _c = -50mA; I _B = 0	-80			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -10mA; I _C = 0	-5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -3A; I _B = -0.3A			-1.7	V
V _{BE} (on)	Base-Emitter On Voltage	I _C = -3A; V _{CE} = -5V			-1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -80V; I _E = 0			-70	μA
I _{EBO}	Emitter Cutoff Current	V_{EB} = -5V; I _C = 0			-0.1	mA
h _{FE-1}	DC Current Gain	I _C = -0.5A; V _{CE} = -5V	40		240	
h _{FE-2}	DC Current Gain	Ic= -3A; V _{CE} = -5V	15			
f⊤	Current-Gain—Bandwidth Product	Ic= -0.5A; Vce= -5V	3			MHz
Сов	Collector Output Capacitance	I _E = 0; V _{CB} = -10V; f= 1MHz		130		μF

h_{FE-1} Classifications

R	0	Y
40-80	70-140	120-240

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